

Frequency Reconfigurable Microstrip Patch Antenna

by

| Name | Roll No. | Registration No: |
|----------------------|--------------------|----------------------------------|
| Ankit Barnwal | 11700314018 | 141170110200 of 2014-2015 |
| Sandip Das | 11700314079 | 141170110261 of 2014-2015 |
| Rohit Shaw | 11700314073 | 141170110255 of 2014-2015 |
| Joy Bagchi | 11700314046 | 141170110228 of 2014-2015 |

A comprehensive project report has been submitted in partial fulfillment of the requirements for the degree of

Bachelor of Technology *in* **ELECTRONICS & COMMUNICATION ENGINEERING**

Under the supervision of

Mrs. Pampa Debnath

Assistant Professor



Department of Electronics & Communication Engineering
RCC INSTITUTE OF INFORMATION TECHNOLOGY
Affiliated to Maulana Abul Kalam Azad University of Technology, West Bengal
CANAL SOUTH ROAD, BELIAGHATA, KOLKATA - 700015

May, 2018

CERTIFICATE OF APPROVAL



This is to certify that the project titled “Frequency Reconfigurable Microstrip Patch Antenna” carried out by

| Name | Roll No. | Registration No: |
|----------------------|--------------------|-------------------------------------|
| Ankit Barnwal | 11700314018 | 141170110200 of 2014-2015 |
| Sandip Das | 11700314079 | 141170110261 of 2014-2015 |
| Rohit Shaw | 11700314073 | 141170110255 of 2014-2015 |
| Joy Bagchi | 11700314046 | 141170110228 of 2014-2015 |

for the partial fulfillment of the requirements for B.Tech degree in **Electronics and Communication Engineering** from **Maulana Abul Kalam Azad University of Technology, West Bengal** is absolutely based on his own work under the supervision of **Mrs. Pampa Debnath**. The contents of this thesis, in full or in parts, have not been submitted to any other Institute or University for the award of any degree or diploma.

.....
Mrs. Pampa Debnath
Assistant Professor , Dept. of ECE
RCC Institute of Information Technology

.....
Dr. Abhishek Basu

Head of the Department (ECE) , RCC Institute of Information Technology

DECLARATION



“We Do hereby declare that this submission is our own work conformed to the norms and guidelines given in the Ethical Code of Conduct of the Institute and that, to the best of our knowledge and belief, it contains no material previously written by another neither person nor material (data, theoretical analysis, figures, and text) which has been accepted for the award of any other degree or diploma of the university or other institute of higher learning, except where due acknowledgement has been made in the text.”

.....

Ankit Barnwal

Registration No: **141170110200** of 2014-
2015

Roll No: **11700314018**

.....

Sandip Das

Registration No: **141170110261** of 2014-
2015

Roll No: **11700314079**

.....

Rohit Shaw

Registration No: **141170110255** of 2014-
2015

Roll No: **11700314073**

.....

Joy Bagchi

Registration No: **141170110228** of 2014-
2015

Roll No: **11700314046**

Date:

Place:

CERTIFICATE of ACCEPTANCE



This is to certify that the project titled “**Frequency Reconfigurable Microstrip Patch Antenna**” carried out by

| Name | Roll No. | Registration No: |
|----------------------|--------------------|----------------------------------|
| Ankit Barnwal | 11700314018 | 141170110200 of 2014-2015 |
| Sandip Das | 11700314079 | 141170110261 of 2014-2015 |
| Rohit Shaw | 11700314073 | 141170110255 of 2014-2015 |
| Joy Bagchi | 11700314046 | 141170110228 of 2014-2015 |

is hereby recommended to be accepted for the partial fulfillment of the requirements for B.Tech degree in **Electronics and Communication Engineering** from **Maulana Abul Kalam Azad University of Technology, West Bengal**

Name of the Examiner Signature with Date

1.

2.....

3.....

4.

Acknowledgement

I heartily acknowledge our Associate Professor, Mrs. Pampa Debnath for guiding us throughout the project and giving us time whenever we needed support.

I wish to thank our Head Of Department, Dr. Abhishek Basu for being a constant motivator and a pillar through the past years we've spent.

There are numerous factors after everyone's breakthrough in one's life. I would like to take this opportunity to thank almost everyone possible.

Our Parents has been of great support throughout the journey in all ways possible, we'd like to thank them promise to be a Human first and then become successful.

All of these wouldn't have been possible without my beloved/my inspiration/Friend/Father Lord *Krishna*, without whose support and blessings anything wouldn't have fallen into place.

Finally I would like to thank all my friends and teachers in the university for their collaboration and support.

ABSTRACT

In Satellite and airborne communication, and ECM system, there has always been a continuous demand for smaller size, lighter weight antenna systems that has properties to achieve selectivity in frequency, bandwidth, polarization and gain.

So, in particular, planar designs enjoy all of these features including smaller size, lower RCS, lower manufacturing cost and surface conformability.

In this project, we'll be working in the frequency range of (0-2.4) GHz which includes it's application in cell phone working in frequency 0.8GHz, wireless applications working in frequency 2.4GHz(not Wi-Max which works in 5.8GHz).

Reconfigurable antenna is capable of operating at more than one frequency band thereby the number of antennas.

CONTENTS

| | |
|--|----|
| CERTIFICATE | 1 |
| Declaration..... | 2 |
| CERTIFICATE Of ACCEPTANCE..... | 3 |
| ACKNOWLEDGEMENT..... | 5 |
| ABSTRACT..... | 6 |
| CONTENTS | 7 |
| LIST OF ABBREVIATIONS & ABBREVIATIONS | 8 |
| LIST OF FIGURES | 9 |
| LIST OF TABLES | 10 |
| 1. Introduction to Frequency Reconfigurable Patch Antenna | |
| 1.1) Introduction | 11 |
| 1.2) Objectives..... | 13 |
| 1.3) Reconfigurable Antenna Classification..... | 14 |
| 1.4) Applications..... | 15 |
| 2. Theory Of Patch Antenna | |
| 2.1) Introduction..... | 17 |
| 2.2) Basic Characteristics..... | 18 |
| 2.3) Radiation pattern..... | 21 |
| 2.4) Polarization..... | 22 |
| 2.5) Bandwidth..... | 23 |

| | | |
|-----------|---|-----------|
| 3. | Microstrip Line | |
| | 3.1)Introduction..... | 25 |
| | 3.2)Microstrip..... | 25 |
| | 3.3)Dispersive Effects..... | 28 |
| | 3.4)Characteristics impedance | 30 |
| | 3.5)Losses in Semiconductor..... | 31 |
| 4. | Antenna Design with HFSS | |
| | 4.1)Introduction..... | 35 |
| | 4.2)Microstrip antenna design using HFSS..... | 35 |
| | 4.3)Design of Microstrip transmission line..... | 38 |
| 5. | Conclusion..... | 40 |
| 6. | REFERENCE..... | 42 |

LIST OF SYMBOLS & Abbreviations

EMI- Electromagnetic Interference

PIFA- Printed Inverted F Antenna

PIL -Printed Inverted L Antenna

FDTD- Finite Difference Time Domain

MPA- Microstrip Patch Antenna

AR -Axial Ratio

TM -Transverse Magnetic

RF -Radio Frequency

RL -Return Loss

EDM- Electrical Discharge Machine

ϵ_{eff} -Effective permittivity

ϵ_r -Relative permittivity

ϵ'' - Imaginary part of the complex permittivity

ϵ' - Real part of complex permittivity

μ_r - Relative permeability

A -Ampere

dB- decibel

E -Electric field vector

H -Magnetic field vector

EM- Electromagnetic

f_r -Resonant frequency

GHz- Giga Hertz

K- Co- efficient of thermal conductivity

Q -Quality Factor

Z₀ -Characteristic impedance

λ_0 -Free space wavelength

LIST OF FIGURES

| | | |
|---------|--|--|
| Fig 1.1 | Microstrip Antenna | |
| Fig 1.2 | Types and shape of Patch Antenna | |
| Fig 1.3 | Typical feeding methods for Microstrip patch antenna | |
| Fig 1.4 | Microstrip Antenna with electric field lines | |
| Fig 1.5 | Rectangular microstrip patch antenna with effective lengths | |
| Fig 1.6 | Basic antenna along with its simulation | |
| Fig 1.7 | Return losses for two basic antenna elements | |
| Fig 1.8 | Layout design for the patch antenna with resonant frequency 2.4GHz | |
| Fig 1.9 | Return loss of the proposed 2.4GHz single patch antenna | |

LIST OF TABLES

| | | |
|------------|--|--|
| Table 1.1 | Dimensions of the Microstrip patch antenna | |
| Table 2.2. | Microstrip antenna basic calculations | |
| Table 2.3. | Transmission line and return Loss | |
| Table 2.4. | Mechanism Contributing to loss | |

Chapter 1

Introduction to Frequency Reconfigurable Antenna

1.1. Introduction

Patch antennas are widely used today. They are used for satellite communications and various military purposes such as GPS, mobile, missile systems, etc., due to their light weight, simple structure and easy implementation. The main advantages of patch antennas are as follows:

- (1) Low cost to fabricate.
- (2) Easy to manufacture.
- (3) Efficient radiation.
- (4) Support both linear and circular polarization.
- (5) Light weight.
- (6) Integrate easily with microwave integration circuits.

The increasing demand for modern mobile, satellite and wireless communication systems have driven many researchers to work on improving performance and enhancing applications of patch antennas. Reconfigurable antennas have drawn much attention for future wireless communication systems due to their ability to modify their geometry to adapt to changes in environmental conditions or system requirements such as enhanced bandwidths, operating frequencies, polarizations, radiation patterns, etc

Microstrip antenna is one of the most popular choices in designing the reconfigurable antenna because of their advantages we introduced above.

A reconfigurable radiation pattern antenna reduces the effects of noisy environments by changing the null positions, and it saves energy by adjusting the main beam signal towards the intended user to improve the overall system performance.

Polarization reconfigurable antennas have drawn increasing attention because they have some desirable advantages for modern wireless communications, such as avoiding fading loss caused by multipath effects in wireless local area networks, providing a powerful modulation scheme in active read/write microwave tagging systems, realizing frequency reuse to expand the capability in satellite communication systems, and being a suitable candidate in multiple-input-multiple-output (MIMO) systems.

There is a developmental trend in wireless communication systems that requires the use of antennas capable of accessing services in various frequency bands, sometimes with the use of a single antenna. So far, most of the reported pattern reconfigurable antennas can only switch the beam in a limited range. And there are few antenna designs concerned with both radiation pattern and dual-frequency. A pattern reconfigurable antenna that has multiband characteristics improves the whole system performance.

1.2. Objectives

The objective of this thesis is designing and testing of frequency reconfigurable microstrip patch antenna with resonating frequency of 2.4GHz.

The antenna can be used for applications operating in the frequency range of (0-2.4)GHz like for cell phones and other wireless devices operating in the mentioned frequency range.

1.3. Reconfigurable antenna classification

A **reconfigurable antenna** is an antenna capable of modifying dynamically its frequency and radiation properties in a controlled and reversible manner. In order to provide a (switches, varactors, mechanical actuators or tunable materials) that enable the intentional redistribution of the RF currents over the antenna surface and produce reversible modifications over its properties. Reconfigurable antennas differ from smart antennas because the reconfiguration mechanism lies inside the antenna rather than in an external beamforming network. The reconfiguration capability of reconfigurable antennas is used to maximize the antenna performance in a changing scenario or to satisfy changing operating requirements.

Frequency Reconfiguration

Frequency reconfigurable antennas can adjust dynamically their frequency of operation. They are particularly useful in situations where several communications systems converge because the multiple antennas required can be replaced by a single reconfigurable antenna. Frequency reconfiguration is generally achieved by modifying physically or electrically the antenna dimensions using RF-switches, impedance loading or tunable materials.

Radiation Pattern Reconfiguration

Radiation pattern reconfigurability is based on the intentional modification of the spherical distribution of radiation pattern. Beam steering is the most extended application and consists in steering the direction of maximum radiation to maximize the antenna gain in a link with mobile devices. Pattern reconfigurable antennas are usually designed using movable/rotatable structures or including switchable and reactively-loaded parasitic elements. In last 10 years, metamaterial-based reconfigurable antennas have gained attention due their small form factor, wide beam steering range and wireless applications.

Polarization Reconfiguration

Polarization reconfigurable antennas are capable of switching between different polarization modes. The capability of switching between horizontal, vertical and circular polarizations can be used to reduce polarization mismatch losses in portable devices. Polarization reconfigurability can be provided by changing the balance between the different modes of a multimode structure.

Compound Reconfiguration

Compound reconfiguration is the capability of simultaneously tuning several antenna parameters, for instance frequency and radiation pattern. The most common application of compound reconfiguration is the combination of frequency agility and beam-scanning to provide improved spectral efficiencies. Compound reconfigurability is achieved by combining in the same structure different single-parameter reconfiguration techniques^{[15][16]} or by reshaping dynamically a pixel surface

1.4. Applications

Reconfigurable antennas find applications in many areas especially when multiple radiation properties are required from a single element. These areas are stated below:

- Cognitive radio
- Plug and play reconfigurable satellites
- Multiple Input Multiple Output (MIMO) communication systems
- Cellular and personal communication systems
- Military applications

As examples to these applications, the antennas in can be used for GSM, DCS, PCS, UMTS, Bluetooth, and wireless local-area network (LAN). The antenna in can reconfigure its radiation patterns by altering its structure, while the resonant frequency and polarization remain unchanged. A lot of the previously stated applications require different radiation pattern changes without affecting the frequency and polarization response.

Chapter 2

Theory of Patch Antenna

2.1. Introduction

A **patch antenna** (also known as a rectangular microstrip **antenna**) is a type of radio **antenna** with a low profile, which can be mounted on a flat surface. It consists of a flat rectangular sheet or "**patch**" of metal, mounted over a larger sheet of metal called a ground plane.

Low profile antennas have drawn much attention because they are suitable for high performance aircraft, spacecraft and satellite and missile applications, where size, weight, cost, performance, ease of installation, and aerodynamic profile are significant constraints. For today's rapidly-developing mobile or personal communication devices, there exists same need for compact and low profile antennas. Microstrip antennas (also referred to as patch antennas or microstrip patch antennas) can be used in a wide range of applications from commercial communication systems to satellites, and even biomedical applications [27]. Chapter 14 of Antenna Theory: Analysis and Design contributes greatly to the fundamentals of patch antenna addressed in this chapter of the thesis.

2.2. Basic Characteristics

The history of patch antenna can be traced back to 1953, when G.A. Deschamps first proposed this kind of antenna. However, patch antennas didn't become practical until the 1970s. In that time, it was developed further by researchers such as Robert E. Munson and others by using low-loss soft substrate materials that were just becoming available during that time.

Based on that, a microstrip antenna (Patch antenna), as shown in Figure 2.1, normally consists of a very thin ($t \ll \lambda_0$ where λ_0 is the free-space wavelength) metallic patch placed a small fraction of a wavelength ($h \ll \lambda_0$, usually $0.003\lambda_0 \leq h \leq 0.05\lambda_0$) above a ground plane. The distance between the patch and the ground plane – the substrate or dielectric height h – determines the bandwidth of antenna. A relatively thicker substrate can increase the gain, but it may result in some undesired effects such as surface wave excitation. Surface waves can decrease efficiency and perturb the radiation pattern. The patch antenna is designed so its pattern maximum is normal to the patch (broadside radiator). This is accomplished by properly choosing the mode (field configuration) of excitation beneath the patch. In general, modes are designated as TM_{nmp} . The 'p' value is mostly omitted because the electric field variation is considered negligible in the z-axis since only a phase variation exists in the z axis. So, TM_{nm} represents the field variations in the x and y directions. The field variation in the y direction (impedance width direction) is negligible and so m is considered 0. The field has one minimum-to-maximum variation in the x direction (resonance length direction and a half-wave long), thus n is 1 in this case, and we say that this patch operates in the TM_{10} mode.

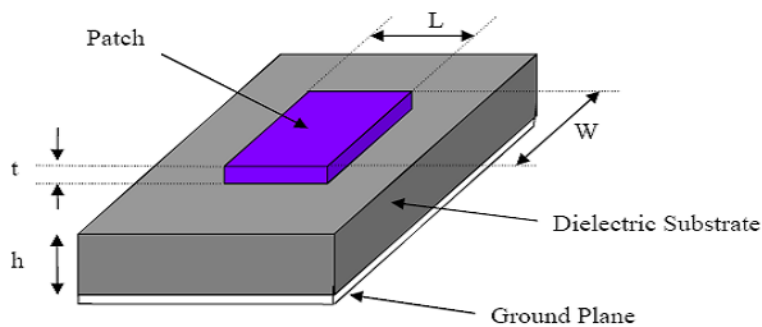


Figure 2.1: Microstrip Antenna

For a rectangular patch, the length L of the element is usually

$$(\lambda_0/3) < h < (\lambda_0/2) .$$

The patch and the ground are separated by a dielectric sheet (usually referred to as the substrate), also

as shown in Figure 2.1.

There are numerous substrates that can be used for the design of microstrip antennas, and their dielectric constants, ϵ_r , are usually in the range of $2.2 \leq \epsilon_r \leq 12$. The most desirable ones for antenna performance are thick substrates with dielectric constants at the lower end of the range because they provide better efficiency, larger bandwidth, and loosely bound fields for radiation into space, but at the cost of large element size. Thin substrate with higher dielectric constants are suitable for microwave circuitry because they require tightly bound fields to minimize undesired radiation and coupling, and result in smaller element size. However, they are less efficient and have a relatively smaller bandwidth because of their great losses. Since microstrip antennas are often integrated with other microwave circuits, a compromise has to be made between good antenna performance and circuit design.

Basically, microstrip antennas are also referred to as patch antenna. Usually, the radiating elements and feed lines of microstrip antennas are photoetched on the dielectric substrate. The radiating patch is generally made of conducting material such as copper or gold and can be any possible shape, such as rectangular, thin strip (dipole), circular, elliptical, triangular, etc. These and others are illustrated in Figure 2.2. Among the possible shapes, the square, rectangular, dipole, and circular are the most common because they are easy to analyze and fabricate. As well, they have other attractive characteristics, especially low cross-polarization radiation. Microstrip dipoles are attractive because they inherently possess a larger bandwidth and occupy less space, which makes them very suitable for arrays. Linear and circular polarization patch antennas can be obtained with either single elements or arrays of microstrip antennas. An array of microstrip elements, with single or multiple feeds, can also be used to introduce scanning capabilities and achieve greater directivities.

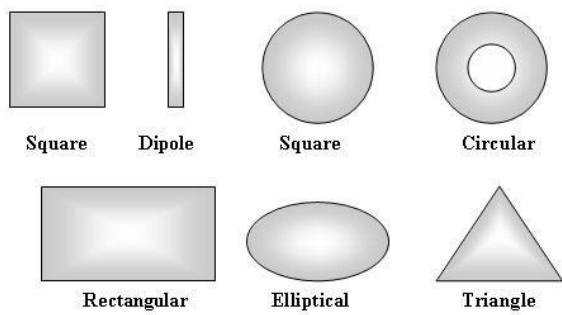


Fig. 2.2 :Different shapes of Patch Antenna

2.3. Radiation Pattern

A patch antenna radiates energy in certain directions and we say that the antenna has directivity (usually expressed in dBi). So far, the directivity usually has been defined relative to an isotropic radiator. An isotropic radiator emits an equal amount of power in all directions and it has no directivity. If the antenna has a 100% radiation efficiency (meaning the energy delivered to the antenna can be 100% radiated from antenna), all directivity would be converted to gain. The typical rectangular patch excited in its fundamental mode has a maximum directivity in the direction perpendicular to the patch (z-axis). The directivity decreases when moving away from zenith direction towards lower elevations. Figure 2.3 shows a typical radiation pattern for half-wave square patch antenna

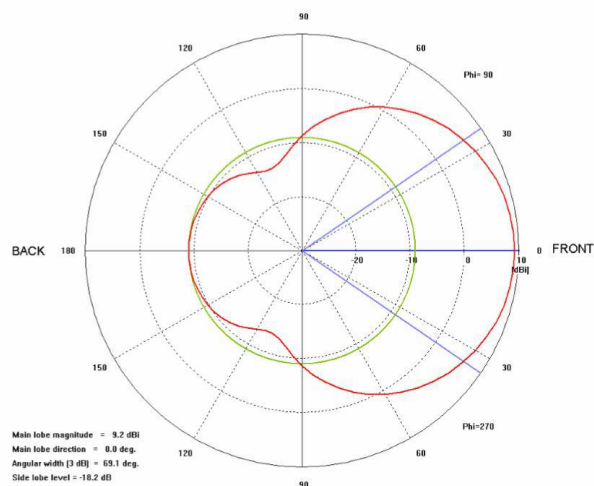


Figure 2.3 Radiation pattern for half-wave square patch antenna

2.4. Polarization

The plane in which the electric field varies is also known as the polarization plane. The basic patch antenna is linearly polarized since the electric field varies in only one direction. However, a large number of applications such as satellite communications, do not work well with linear polarization because, due to the moving antenna platform, the relative orientation of the antenna is unknown. In these applications, circular polarization is useful since it is not sensitive to antenna orientation. Basic antennas do not generate circular polarization; hence some changes have to be made to the patch antenna to enable it to generate circular polarization. For a circularly polarized patch antenna, the electric field varies in two orthogonal planes (x and y directions) with the same magnitude but a 90° phase difference, as shown in Figure 2.4. Necessary to generate circular polarization for a patch antenna is the simultaneous excitation of two modes, i.e. the TM₁₀ mode (x direction) and the TM₀₁ mode (y direction). One of the modes is excited with a 90° phase delay to the other mode. A circularly polarized antenna can either be right-hand circular polarized (RHCP) or left-hand circular polarized (LHCP). The antenna is RHCP when the phases are 0° and -90° for the antenna in Figure 2.4, and the signal radiates towards the reader. It is LHCP when the phases are 0° and $+90^\circ$, and the signal radiates away

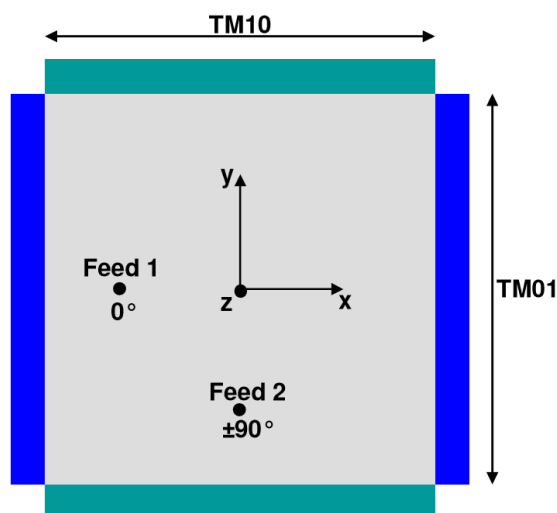


Figure 2.4 The nearly square antenna for circular polarization

2.5. Bandwidth

The impedance bandwidth depends on a large number of parameters related to the patch antenna element itself like quality factor, Q , and the type of feed technology used. Usually, the impedance bandwidth of a square, half-wave patch antenna is typically limited to 1 to 3%, which is a major disadvantage of this type of patch antenna.

Chapter 3

Microstrip Line

3.1. Introduction

Microstrip technology is quite mature, offering a superior blend of performance characteristics to the designer of the microwave integrated circuit. Nearly 50 references at the end of this article attest to the number of investigators who have published design formulas for microstrip. So today, the problem is not the circuit designer lacks information concerning this transmission medium, but that too much information is available, scattered throughout many journals. What follows is an attempt to review the most useful formulas and conclusions, and arrange them in a logical, easy-to-follow order.

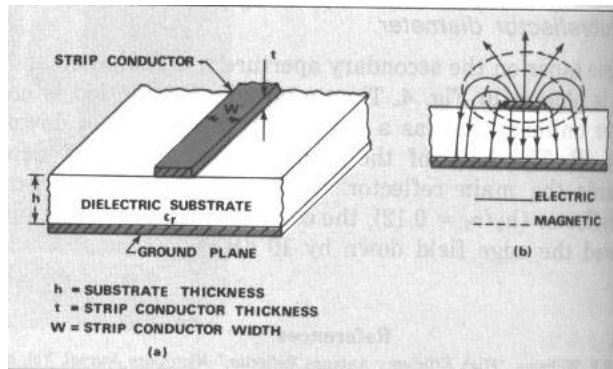
But first, understand the difference between microstrip and other forms of MCI transmission that are often erroneously referred to as "microstrip." By definition, a microstrip transmission line consists of a strip conductor and a ground plane separated by a dielectric medium. The dielectric material serves as a structural substrate upon which a thin-film metal conductor is deposited. Conductors are usually gold or copper.

3.2. Microstrip

Since field lines between the strip and the ground plane are not contained entirely in the substrate, the propagating mode along the strip is not purely transverse electromagnetic (TEM) but quasi-TEM. Assuming the quasi-TEM mode of propagation, the phase velocity in microstrip is given by

$$V_p = c / \sqrt{\epsilon_{\text{eff}}}$$

Where c is the velocity of light, and E_{eff} is the effective dielectric constant of the substrate material. The effective dielectric constant is lower than the relative dielectric constant, E_r , of the substrate, and takes into account external fields.



the wavelength, λ_g in microstrip line is given by

$$\lambda_g = V_p / f$$

Where V_p is given by Eq.1 and f is frequency.

The characteristic impedance of the transmission line is given by

$$Z_0 = 1 / V_p C$$

Where C is the capacitance per unit length of the line.

The analysis for the evaluation of E_{eff} and C based on quasi-TEM mode is fairly accurate at lower microwave frequencies. At higher frequencies, the ratio of longitudinal-to-transverse electric field components becomes significant and the propagating mode can no longer be considered quasi-TEM.

Closed-form expressions are vital

Early attempts to characterize the performance of microstrip lines were based on the quasi-TEM model. Various electrostatic approximations such as conformal mapping, relaxation methods, variational techniques, the method of green functions and the moment method are generally used. Closed form expressions are absolutely necessary for optimization

and computer aided design of a micro strip circuit.

The closed form expression for Z_0 and E_{eff} have been reported by Wheeler , Schneider and Hammerstad . Wheeler and Hammerstad have also given an expression for W/h in terms of Z_0 and E_r . For a practical range of microstrip line ($0.05 \leq W/h \leq 20$ and $E_r \leq 16$) Hammerstad reported that his expression are more accurate than earlier work ,and fall within +1 and -1 per cent of wheeler's numerical results . His expression, which are based on work of Wheeler and Schneider ,includes useful relationships defining both characteristic impedance and effective dielectric constant:

For $W/h \leq 1$,

$$Z_0 = 60 \ln(8 h/W + 0.25 W/h) / \sqrt{E_{eff}} \quad (4)$$

where

$$E_{eff} = ((E_r + 1)/2) + ((E_r - 1)/2) * [(1 + 12 h/W)^{-1/2} + 0.04(1 - W/h)^2] \quad (5)$$

For $W/h \geq 1$

$$Z_0 = (120 \pi / \sqrt{E_{eff}}) / (W/h + 1.393 + 0.667 \ln(W/h + 1.444)) \quad (6)$$

where:

$$E_{eff} = ((E_r + 1)/2) + ((E_r - 1)/2) * [(1 + 12 h/W)^{-1/2}] \quad (7)$$

Hammerstad notes that the maximum relative error in E_{eff} and Z_0 is less than +0.5

per cent and 0.8 per cent, respectively, for $0.05 \leq W/h \leq 20$ and $E_r \leq 16$. His expression for W/h in terms of Z_0 and E_r

are:

for $W/h \leq 2$

$$W/h = 8 \exp(A) / \exp(2A) - 2$$

for $W/h \geq 2$

$$W/h = 2/\pi [B - 1 - \ln(2B - 1) + (E_r - 1)/E_r] \{ \ln(B - 1) + 0.39 - 0.61/E_r \}$$

where

$$A = Z_0 / 60 (\sqrt{\epsilon_r + 1} / 2) + (\epsilon_r - 1) / (\epsilon_r + 1) (0.23 + 0.11 / \epsilon_r)$$

$$B = 377 \pi / 2 Z_0$$

These expressions provided the same accuracy as Eqs 4, 5, 6 and 7.

The results discussed above assumed a two-dimensional strip conductor. However, when $t/h \leq 0.005$, $2 \leq \epsilon_r \leq 10$ and $0.1 \leq W/h \leq 5$, the agreement between experimental and theoretical ($t/h=0$) result is excellent.

Expressions for W_e are:

For $W/h \geq 1/2 \pi$

$$W_e/h = W/h + t/\pi h (1 + \ln(2h/t)) \quad (10)$$

For $W/h < 1/2 \pi$

$$W_e/h = W/h + t/\pi h (1 + \ln(4\pi W/t)) \quad (11)$$

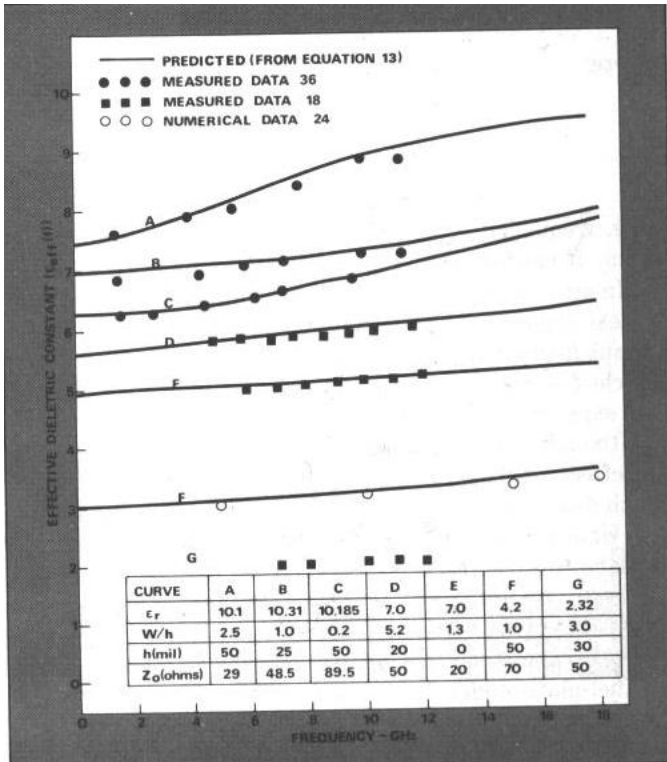
Additional restrictions for applying Eqs 10, 11 are $t \leq h$ and $t < W/2$. Typical strip thickness varies from 0.0002 to 0.0005 inch for metalized alumina substrate, and from 0.001 to 0.003 inch for low dielectric substrates.

Most micro wave integrated circuit applications require a metallic enclosure for hermetic sealing, strength, electromagnetic shielding and ease of handling. But when the ratio of the distance between the lower and upper to substrate thickness is larger than five.

3.3. Dispersive effects

Consider dispersion at higher frequencies

The formulas for characteristic impedance and effective dielectric constant presented thus far have been based on a quasi-TEM mode of propagation. At lower frequencies, this is a good static approximation of a dynamic structure. This dispersive characteristic is due to propagation of hybrid modes.



Dispersive effects raise the effective dielectric constant slightly as frequency is increased.

The numerical analysis for dispersion in shielded as well as open microstrip transmission has been treated extensively. The numerical approach is not convenient for microstrip circuit design and therefore, not discussed in the paper.

Both experimental and empirical attempts to describe microstrip dispersion have also been reported. Analytical formulas for dispersion which agree closely with experimental and numerical results have appeared just recently.

These analytical expressions, by Getsinger and Carlin, are very similar, but the results given by Getsinger are closer to experimental as well as numerical results. The dispersion in E_{eff} is given by

$$E_{eff}(f) = \epsilon_r - (\epsilon_r - E_{eff}) / (1 + G(f/f_p)^2) \quad (13)$$

where:

$$f_p = Z_0 / (8 \pi h)$$

$$G = 0.6 + 0.009 Z_0$$

Here frequency, f , is in GHz and substrate thickness, h , in cm. High-impedance lines on thin substrates are less dispersive. There is a close agreement between the calculated values and experimental values.

Although many researchers have attempted to describe the effect on dispersion on

E_{eff} , there are fewer analyses which deal with frequency dependent behaviour of Z_0 . The agreement between the results given by these two analyses is reasonably good.

Recently, closed-form expressions for $Z_0(f)$ based on a parallel-plate model of microstrip line have been reported. These expressions are:

$$Z_0(f) = 377h / (W_{eff}(f) \sqrt{E_{eff}(f)}) \quad (14)$$

The effective width, $W_{eff}(f)$, is given by

$$W_{eff}(f) = W + ((W_{eff}(0) - W) / (1 - (f/f_p)^2)) \quad (15)$$

Where $W_{eff}(0)$ is obtained from Eq 14 when $f=0$.

The variation in characteristic impedance with frequency. The solid curve is arrived at using Eqs 14 and 15, while the dotted curve is the one reported by Knorr and Tufekcioglu. The increase in $Z_0(f)$ is only 4 percent from DC to 10 GHz which is quite small. This change cannot be confirmed experimentally since, at 10 GHz, transistors pose a considerable problem in accurate measurement. Therefore, the effect of dispersion on Z_0 can be generally neglected.

3.4. Characteristic Impedance

Two mechanisms contribute to loss

Attenuation constant, 'a', is one of the most important characteristics of any transmission line. There are two sources of dissipative losses in microstrip circuit: conductor loss and substrate dielectric loss. The conductor loss may be approximated as:

$$a_c = 8.68 R_s / (Z_0 W) \text{ dB/cm} \quad (16)$$

where R_s is surface resistivity.

It should be noted that this simple expression for conductor loss is valid only for very wide strips. However, Eq 16 can be brought closer to reality by considering nonuniform current distribution.

For $W/h \leq 1/2 \pi$,

$$a_c = (8.86 R_s / 2 \pi Z_0 h) * P * [1 + (h/W \epsilon) + (h/\pi W \epsilon) (\ln(4\pi W/t) + (t/W))] \quad (17a)$$

For $1/2 \pi < W/h \leq 2$,

$$a_c = (8.86 R_s / 2 \pi Z_0 h) * P * Q \quad (17b)$$

For $W/h \geq 2$,

$$a_e = (8.86 R_s / Z_0 h) * Q * [W_e/h + (2/\pi) \ln\{2\pi t e(W_e/2h + 0.94)\}^{-2} [W_e/h + W_e/\pi t h / (W_e/2h + 0.94)] \quad (17c)$$

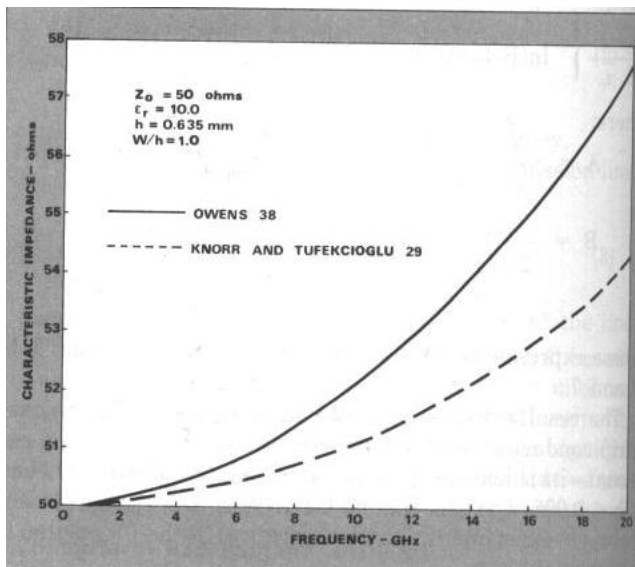
where:

$$P = 1 - (w_e/4h)^2$$

$$Q = 1 + h/W_e + h/\pi W_e (\ln 2h/t - t/h)$$

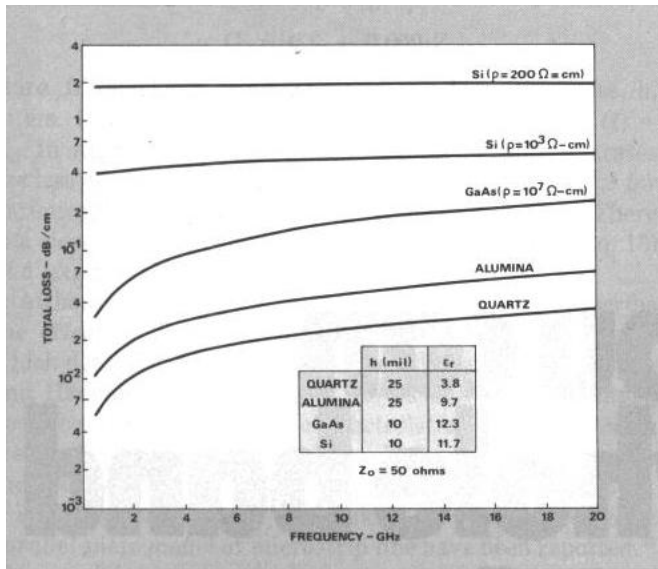
The dielectric loss in microstrip line is an important parameter when microwave circuits requiring small attenuation are considered. Dielectric losses are very small compared with conductor losses for dielectric substrate. Dielectric losses in silicon substrates, however, are usually same order as, or larger than conductor losses. Higher resistivity can be maintained in GaAs, and hence the losses are less for this material.

Figure 4 compares the total loss for 50-ohm microstrip lines on silicon, GaAs, alumina and quartz substrate. It is obvious from the figure that silicon MICs are more lossy. Lines on quartz have the least loss.



Characteristic impedance increases somewhat with frequency. But note that it is only a 4% change from DC to 10GHz.

3.5. Losses in Semiconductor substrates



Losses in semiconductor substrate are substantially higher than those in ceramic or quartz material. Silicon introduces high losses due to the difficulty of growing high resistivity of material.'

Quality factor depends on substrate

The quality factor, Q , of a microstrip line can be related to the total losses in the line by

$$Q_T = B/2a\tau \quad (19)$$

Where Q_T is a total resonator Q , $a\tau$ is the total loss in the resonator and $B = 2\pi \lambda_g$.

When the losses in a resonant are considered another loss factor, $a\tau$, due to radiation at the discontinuities must also be considered. The corresponding radiation Q -factor is given by

$$Q_r = Z_0 / (480\pi (h/\lambda_0)^2 F) \quad (20)$$

where

$$F = (E_{eff}(f) + 1) / E_{eff}(f) - ((E_{eff}(f) + 1)^2 / 2(E_{eff}(f))^{2/3} * \ln(\sqrt{E_{eff}(f)}) + 1 / (\sqrt{E_{eff}(f)})) - 1$$

The total Q of the resonator can be expressed by

$$1/Q_T = 1/Q_c + 1/Q_d + 1/Q_r \quad (21)$$

Here Q_c , Q_d and Q_r are the quality factor corresponding to conductor, dielectric and radiation loss, respectively. Finally, the circuit quality factor, Q_0 , can be defined as

$$1/Q_0 = 1/Q_c + 1/Q_d = \lambda_0(a_c + a_d)/(\pi \sqrt{\epsilon_{eff}}) \quad (22)$$

The variation of Q_0 , Q_r and Q_T with frequency for a quarter-wave resonator on GaAs, alumina and quartz substrates. A quarter-wave, 50-ohm resonator on 25-mil-thick alumina substrate has a Q_0 of about 240 at 2 GHz and 550 at 10 GHz, whereas Q_T is 230 at 2 GHz and nearly 160 at 10 GHz. A quarter-wave, 50-ohm resonator on 10-mil-thick GaAs substrate has Q_0 of about 82 at 2 GHz and 160 at 10 GHz, whereas Q_T is 82 at 2 GHz and nearly 145 at 10 GHz. Thus, a commonly accepted rule for high-Q microstrip circuit using thick substrate does not apply due to high radiation losses incurred under this condition.

Moding limits high frequency operation

Maximum frequency of operation in microstrip line is limited by the excitation of spurious modes in the form of surface waves and transverse resonances. Surface waves are TE and TM modes which propagate across a dielectric substrate with ground plane. The frequency at which significant coupling occurs between the quasi-TEM mode and the lowest order surface wave mode is given by

$$f_r = c/2\pi h \sqrt{2/(\epsilon_r - 1)} \tan^{-1}(\epsilon_r) \quad (23)$$

For $\epsilon_r > 10$, Eq. (23) reduces to

$$f_r(\text{GHz}) = 10.6/h(\text{cm}) \sqrt{\epsilon_r} \quad (24)$$

Cut-off frequency, f_r , decreases when either the substrate thickness or dielectric constant is increased.

Thus, three limitations: maximum substrate thickness, minimum Q and surface wave excitation - define a region of useful microstrip line operation.

For $\epsilon_r = 9.7$, this range is:

$$0.23 \leq h \leq 1.8 \text{ cm @ 2GHz}$$

$$0.01 < h \leq 0.36 \text{ cm @ 10GHz}$$

$$0.01 < h \leq 0.17 \text{ cm @ 20GHz}$$

In addition to the conductor and dielectric losses, the maximum Q of microstrip is also limited by radiation losses from discontinuities. When radiation losses are taken into account for calculation of maximum Q , the plot in Fig. 6 are slightly modified. But, if packaging and circuit design techniques are employed to reduce radiation losses, the curves in Fig. 6 will remain valid.

Chapter 4

Antenna Design with HFSS

4.1. Introduction

Here is a simplified Microstrip antenna design with Ansys HFSS.

There are few basic things that must be known before designing an antenna in general such as:

The frequency range in which the antenna is planned to be propagating, the size of the antenna, the material, the gain of the antenna and the structure of the antenna.

4.2 Microstrip Antenna design with HFSS

We will attempt to design a frequency reconfigurable microstrip patch antenna with the following characteristic:

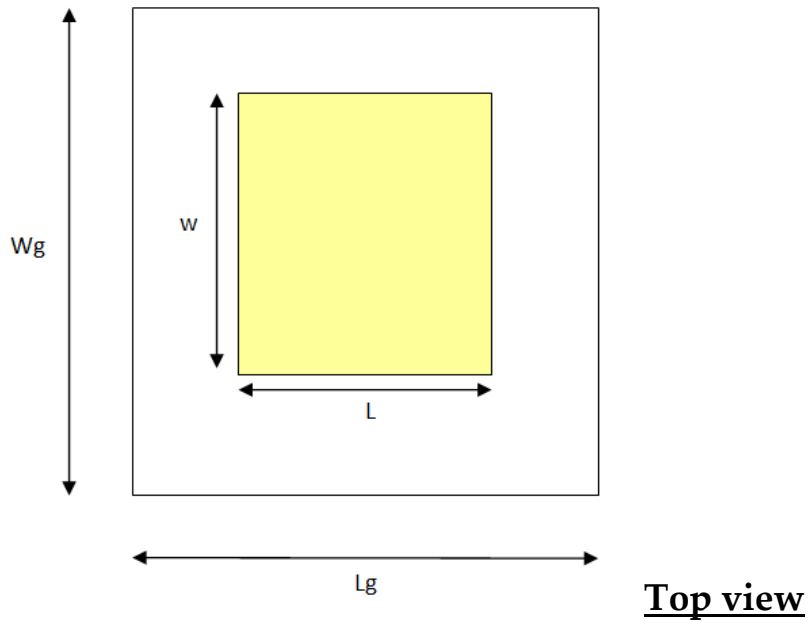
Resonant frequency:- 2.4GHz.

Transmission line impedance: 50 Ohm.

The dielectric constant of the substrate: $\epsilon_r = 2.3$ (Rogers RT/duroid 5880)

Thickness of dielectric substrate (h) : 0.787 mm

Relative Permittivity :-2.2 and Relative Permeability: 1



Wg: Height of the ground plane

W: Height of the path

L: Width of the patch

Lg: Width of the group plane

The following step will be the derivation of other dimensions using the characteristic of the antenna

Microstrip Antenna design with Ansys HFSS

Height of a dielectric constant

$$w = \frac{c}{2f_0 \sqrt{\frac{(\xi_r + 1)}{2}}}$$

$$c = 3.10^8 \text{ m/s}$$

$$w = 30\text{mm}$$

Effective dielectric constant ξ_{eff}

$$\xi_{\text{eff}} = \frac{\xi_r + 1}{2} + \frac{\xi_r - 1}{2} \left[1 + 12 \frac{h}{w} \right]^{-1/2}$$

$$\xi_{\text{eff}} = 10.70$$

Effective length

$$L_{eff} = \frac{c}{2f_0 \sqrt{\xi_{eff}}}$$

$$L_{eff} = 23.27mm$$

Length extension

$$\Delta L = 0.412h \frac{(\xi_{eff} + 0.3) \left(\frac{w}{h} + 0.264 \right)}{(\xi_{eff} - 0.258) \left(\frac{w}{h} + 0.8 \right)}$$

$$\Delta L = 0.67mm$$

Actual length of the path

$$L = L_{eff} - 2\Delta L$$

$$L = 22mm$$

Ground plane dimensions

$$L_g = 6h + L$$

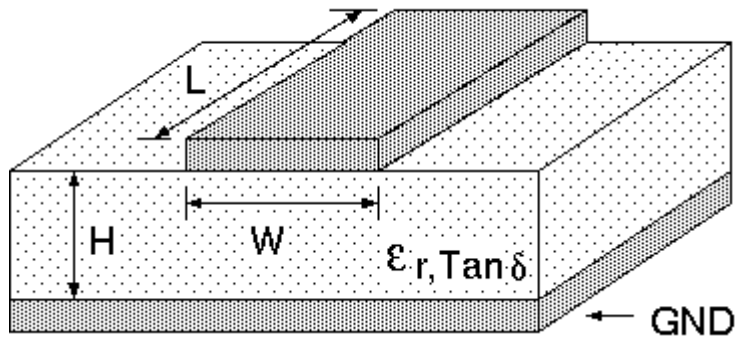
$$W_g = 6h + w$$

$$L_g = 31.6mm$$

$$W_g = 39.6mm$$

Now that we have all dimensions of the antenna, We need to design a transmission line to feed the antenna.

4.3. Design Of Microstrip Transmission line



The characteristic impedance Z_0 is a function of the ratio W/H and

When $\frac{W}{H} \geq 1$

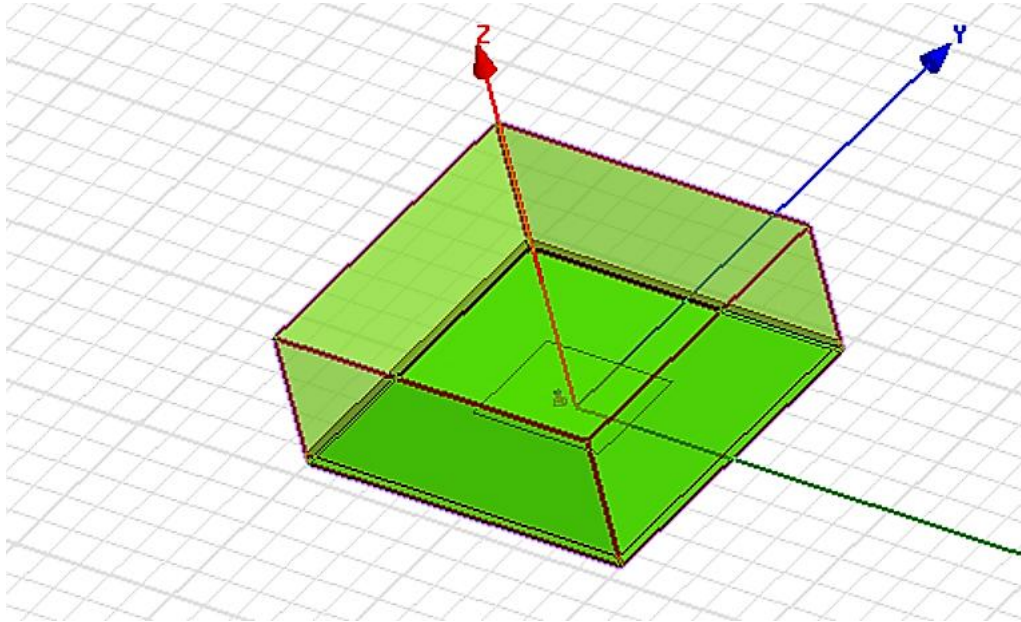
$$Z_0 = \frac{120\pi}{\sqrt{\xi_{eff}} \times \left[\frac{W}{H} + 1.393 + \frac{2}{3} \ln \left(\frac{W}{H} + 1.444 \right) \right]} \text{ (ohms)}$$

Since the value of the Z_0 is proportional to the W/H , we can alternatively change W and H and keep the value of Z_0 more or less constant. This is made for the sake of finding a value that will allow the transmission line to match our others dimensions.

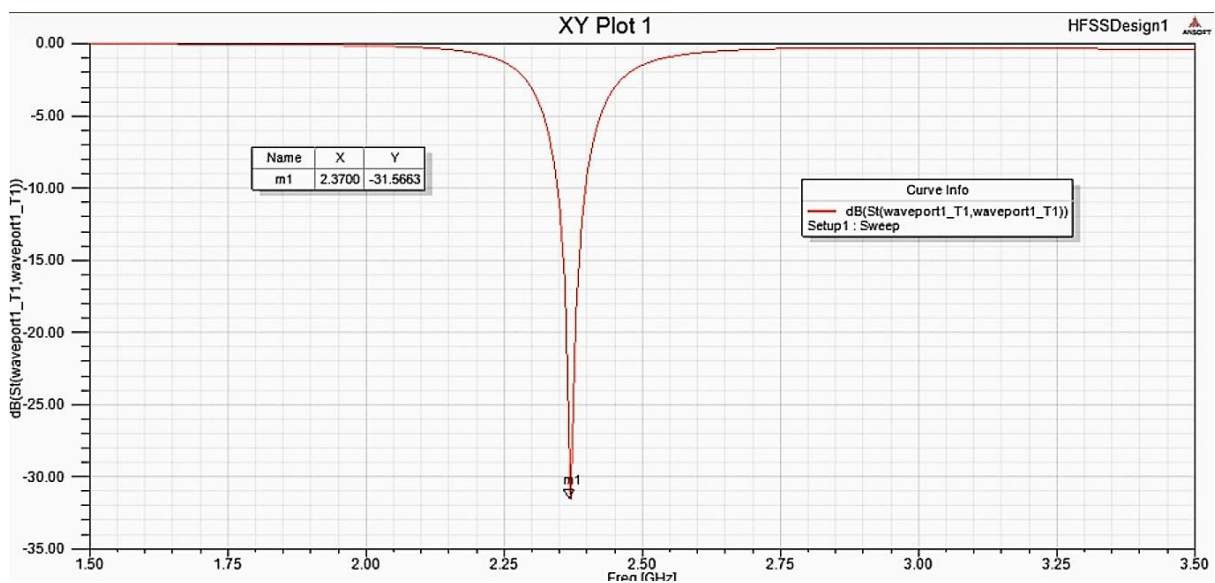
Using the following table, we observe that we have a choice between several W and H while keeping the Z_0 almost constant.

Our concern here was to reduce the height as much as possible to help the whole (transmission line + radiating element) fit nicely on the ground plane.

We will then choose the last value for the antenna design: H=6 mm, W=2.8 mm

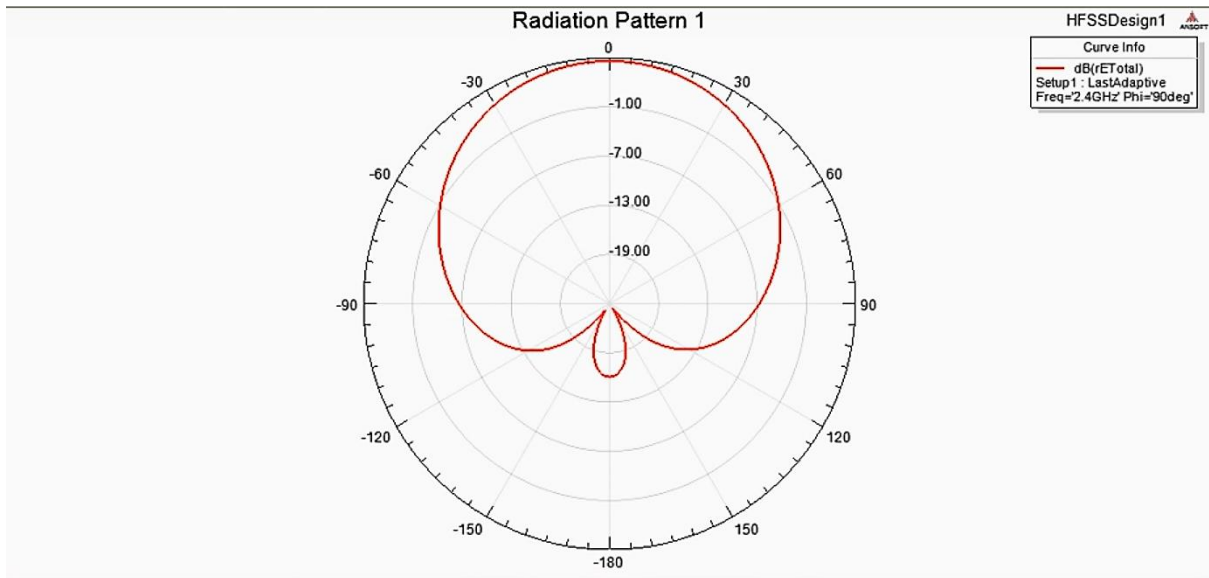


We now need to simulate the microstrip transmission line and make sure the return loss is ok.



The plot above shows a return loss way under -31.3 dB for our chosen dimensions which confirms the design of a 50 ohms microstrip transmission line.

Radiation Pattern is:



Conclusion:

In this work three major reconfigurable antenna's research characteristics are addressed. The first aspect is the design of reconfigurable antennas. These antennas are reviewed, classified and grouped. They are categorized into different groups based on their reconfiguration techniques and they are classified based on their reconfigurability properties. Previous reconfigurable antenna designs, their reconfiguration techniques and their applications are reviewed.

Frequency reconfigurable microstrip patch antenna was designed to cater wireless applications in operating in the frequency range of (0-2.4) GHz.

The plot shows a return loss way under -35.0 dB for our chosen dimensions which confirms the design of a 50 ohms microstrip transmission line.

Reconfigurable antenna designers need to answer a very important question: will they be able to achieve their design objectives in the most efficient and less expensive way. This work tries to answer this question knowing that a designer has to always compromise between improved performance of an antenna and an increased complexity in its structure.

References

- 1.) <http://www.computeraideddesignguide.com>
- 2.) <http://www.radio-electronics.com/info/antennas/basics/resonance.php>
- 3.) <https://ieeexplore.ieee.org/abstract/document/4258985/>
- 4.) <https://ieeexplore.ieee.org/abstract/document/383981/>
- 5.) Bahl and Trivedi book titled " A designer guide to Microstrip line" microwaves, May 1977, pp 174-182
- 6.) Wikipedia
- 7) J.T. Bernhard "Micromachined ,Reconfigurable Out Of Plane Microstrip Patch Antenna Using Plastic Deformation Magnetic Actuation" *IEEE*
- 8) Youtube.com